

Low Power CMOS Dynamic Latch Comparator using 0.18 μ m Technology

Rahul Singh^{*1}, and Arun Sharma²

ABSTRACT

The design and analysis of low power, high speed CMOS dynamic latch comparator is presented. The comparator combines the features of both, the resistive dividing network and differential current sensing comparator. The proposed design will improve the comparator performance by reducing the propagation delay, power dissipation. Simulation results are obtained in 0.18 μ m with supply voltages of 1.8v respectively. The schematic of comparator is captured using Cadence Virtuoso schematic editor and simulated using the Cadence Spectre simulator.

Key words : ADC, Charge sharing network, latch comparator, charge sharing comparator, low power consumption.

1. INTRODUCTION

A Comparator is a circuit that compares an analog signal with another analog signal or reference & outputs a binary signal based on comparison. The comparator is widely used in process of converting analog signals into digital signals. Low power consumption is an important feature of many A to D converters especially those used in portable devices that have limited power supply energy. A common technique to reduce its power is the adoption of a latch comparator design. Dynamic latch comparator can solve the power problem by removing the pre-amplifying stage [1], while achieving a smaller area. This paper focuses on charge sharing comparator as it combines the advantages of both, resistive dividing comparator & differential current sensing comparator.

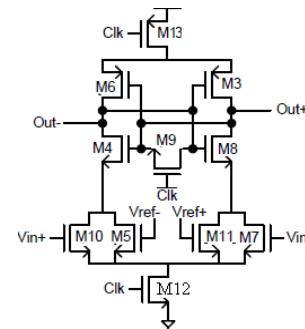


Fig. 1. CMOS charge sharing topology for dynamic latch comparator[4].

Fig.1 shows the charge sharing topology for dynamic latch comparator [4]. In the fig.1, nMOS transistor M12 is used in series with resistive comparing circuit for regenerative mode in order to achieve low power. For reset mode pMOS pre charging circuit is absent and nMOS transistor M9 for output pass transistor for the equalization of both the voltages nearly to $V_{dd}/2$. Now, when the clock goes low, V_{dd} and ground both will be disconnected from the latch with the help of transistors M12 & M3.

1*. Rahul Singh, Electronics and Communication Engg., School of Management Sciences, Technical Campus, Lucknow-227125,(U.P.)-India, email-rsingh.nitk@gmail.com

2. Arun Sharma, Electronics and Communication Engg., School of Management Sciences, Technical Campus, Lucknow-227125,(U.P.)-India, email-pssarun6891@gmail.com

2. DESIGN OF THE COMPARATOR

The flow chart shows in Fig. 1 shows the step of designing the low power CMOS charge sharing dynamic latch comparator using 0.18µm technology:

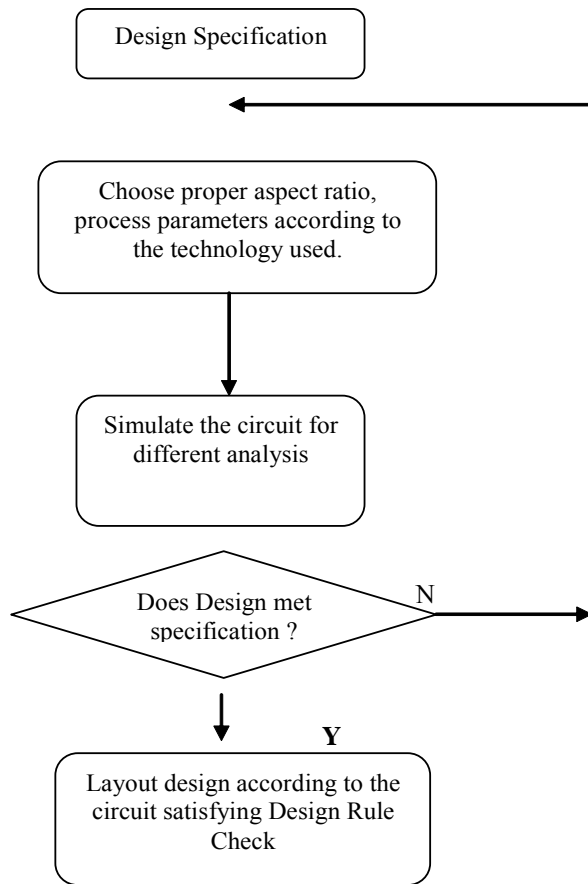


Fig. 2. Flow chart for designing of comparator

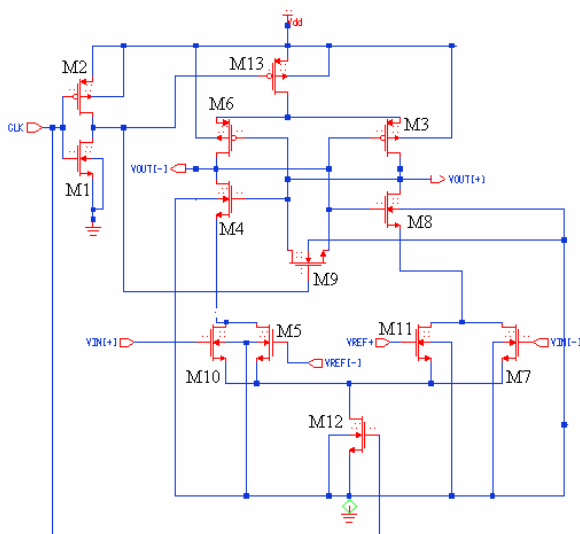


Fig. 3. Design of comparator

Fig. 3 shows the simulated output voltage waveform of this circuit when $V_{ref+} = V_{ref-} = 0.9V$ and $V_{in+} = V_{in-} = 1.8V$ is a square wave. The parameters of all the transistors are shown in Table I.

Table-I
CMOS Transistor Parameter

| | All PMOS | All NMOS |
|---------------|----------|----------|
| Width | 8µm | 4µm |
| Length | 0.18µm | 0.18µm |

If the input of the comparator is greater than the reference voltage, V_{ref} , it has to give an output of '1' and if the comparator input is less than reference voltage then the output of the comparator should be '0'.

3. SIMULATION RESULTS

Simulation of proposed design is done using the 0.18µm CMOS technology. In this project, 1.8V supply voltage is used for operation and clock period is 10ns. During the process, speed of the comparator is 100MHz. This design can be used where low power, high speed and low propagation delay are the main requirements. Finally simulation results of the comparator are shown in Fig. 4. The width of the transistor used is as in the Table I. This simulation result is compared to the previous work [2]. Table III shows the comparison of present design results with previous work and shows an improvement in the present results.

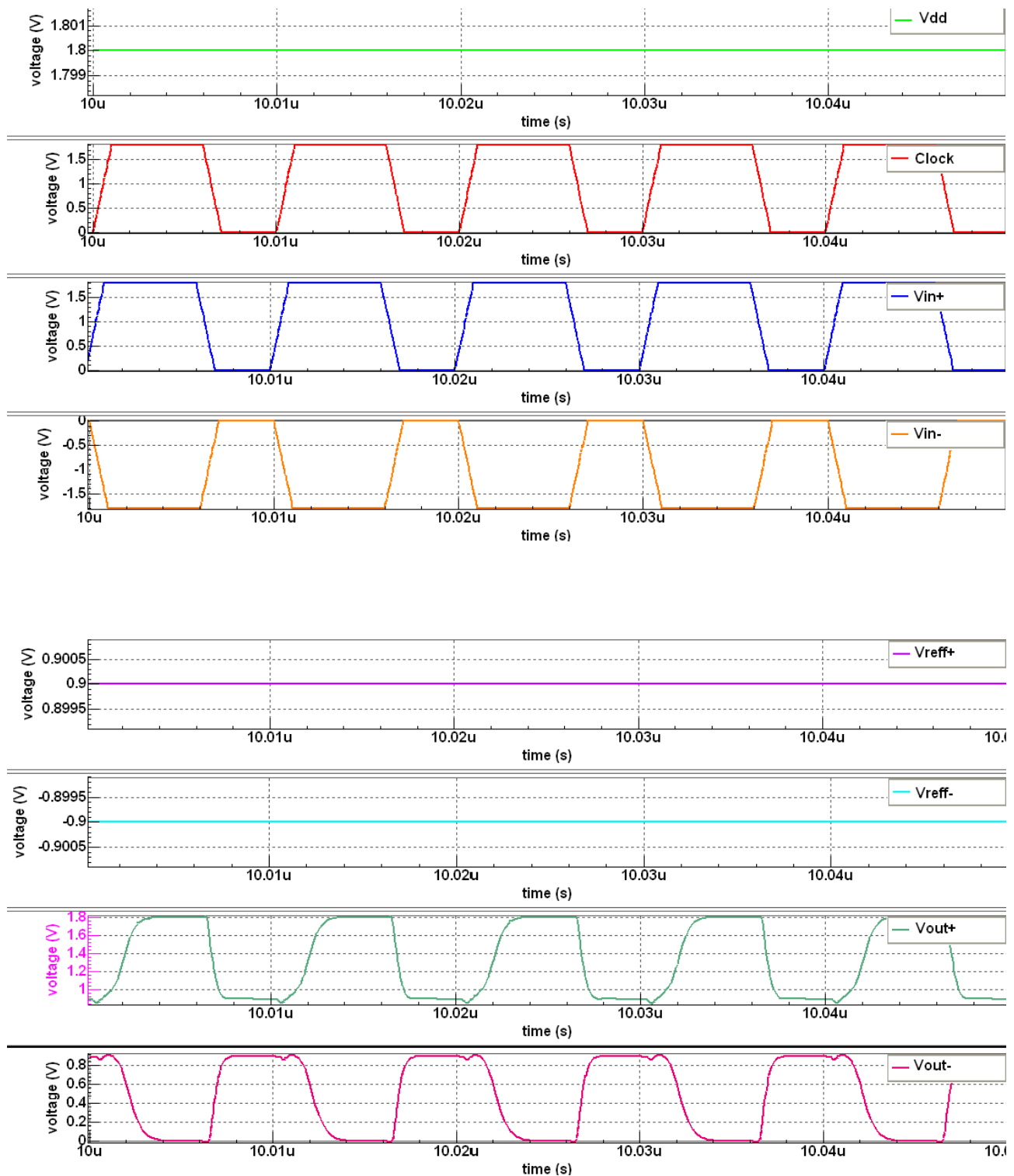


Fig. 4. Transient response

4. CONCLUSION

This paper has presented the CMOS charge sharing dynamic latch comparator design and its simulation results of high speed, and low power by considering 1.8V power supply. The comparison has been done between the previous and present work and the improvements are shown in Table II. In conclusion, the proposed design reduces the power dissipation without deteriorating the comparing speed. From simulation result the power dissipation reduced approximately 92% compared to the previous work and minimize the delay approximately 15%. The proposed design of the comparator runs faster and

High Speed CMOS Comparator in Deep Sub-micron Technology”, M.Tech thesis, Dept. of electronics & communication Eng. Nirma University, 2010.

- [6] N. H. E. Weste and D. F. Harris, CMOS VLSI design: a circuits and systems perspective: Pearson/Addison-Wesley, 2005.

Table-II

| | Previous work | Present work |
|-------------------|---------------|--------------|
| Length | 0.5µm | 0.18µm |
| W_p / W_n | 10µm/5µm | 8µm/4µm |
| Voltage supply | 3.3V | 1.8V |
| Delay | 1.827ns | 1.54ns |
| Power dissipation | 23.18nW | 1.79nW |

provides more stable output signal than the previous work with low supply voltage.

REFERENCES

- [1] P. Uthaichana and E. Leelarasmee, “Low Power CMOS Dynamic Latch Comparators,” IEEE, pp. 605-608, 2003.
- [2] Z. Huang and P. Zhong, “An Adaptive Analog-to-Digital Converter Based on Low-Power Dynamic Latch Comparator,” IEEE conference, p. 6pp, 2005.
- [3] Ili Shairah Abdul Halim,, Nurul Aisyah Nadiah Binti Zainal Abidin, A’zraa Afhzan Ab Rahim,” Low Power CMOS Charge Sharing Dynamic Latch Comparator using 0.18µm Technology. IEEE pp. 156-160, 2011.
- [4] Christopher J. Lindsley “A Nano-Power Wake-Up Circuit for RF Energy Harvesting Wireless Sensor Networks”, M.S. thesis, Dept. Electrical & computer. Eng., Oregon State University 2008.
- [5] Priyesh P. Gandhi “Design & Simulation of Low Power